

Supporting Information

“Cu₃-Cluster-Doped Monolayer Mo₂CO₂ (MXene) as an Electron Reservoir for Catalyzing a CO Oxidation Reaction”

Cheng Cheng,[†] Xilin Zhang,[†] Zongxian Yang,^{*,†,‡} and Zhen Zhou[§]

[†]College of Physics and Materials Science and [‡]National Demonstration Center for Experimental Physics Education, Henan Normal University, Xinxiang, Henan 453007, China

[§]School of Materials Science and Engineering, National Institute for Advanced Materials, Institute of New Energy Material Chemistry, Collaborative Innovation Center of Chemical Science and Engineering (Tianjin), Nankai University, Tianjin 300350, China

E-mail: yzx@henannu.edu.cn (Z.Y.).

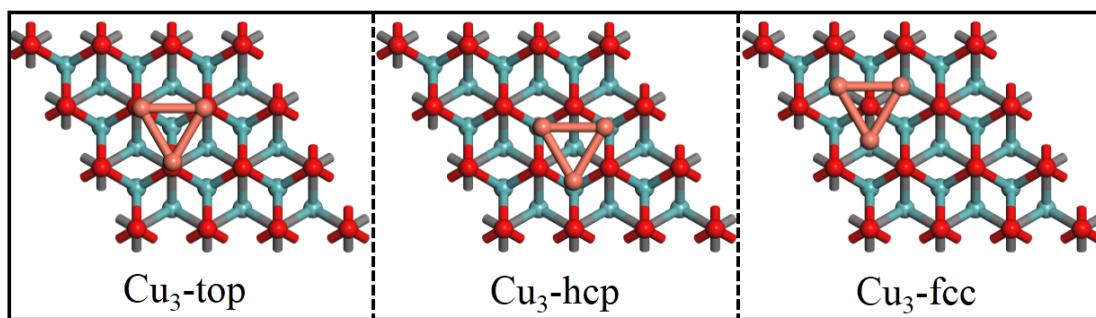


Figure S1. Three deposited sites of Cu_3 cluster on the pristine Mo_2CO_2 monolayer.

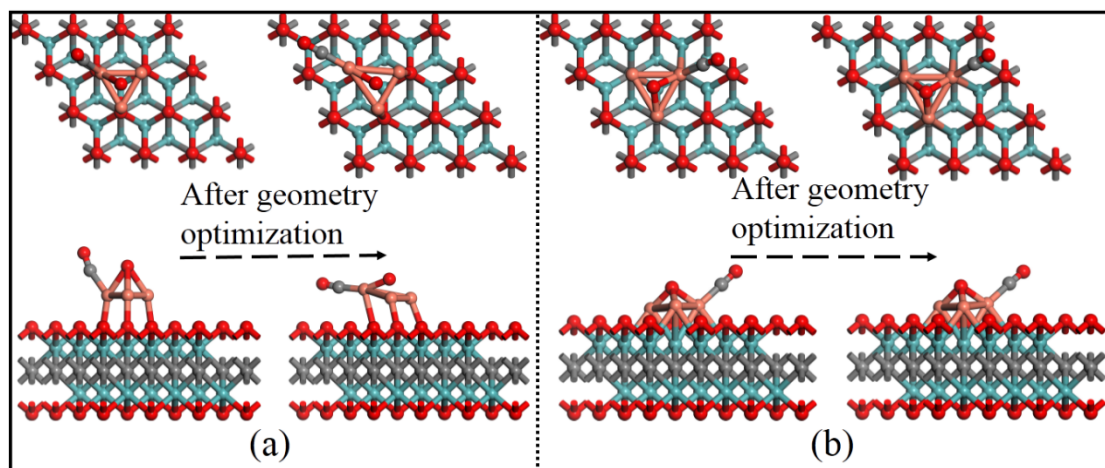


Figure S2. The co-adsorption of O and CO atoms on (a) $\text{Cu}_3/\text{p-Mo}_2\text{CO}_2$ and (b) $\text{Cu}_3/\text{d-Mo}_2\text{CO}_2$ configurations, before and after geometry optimization.

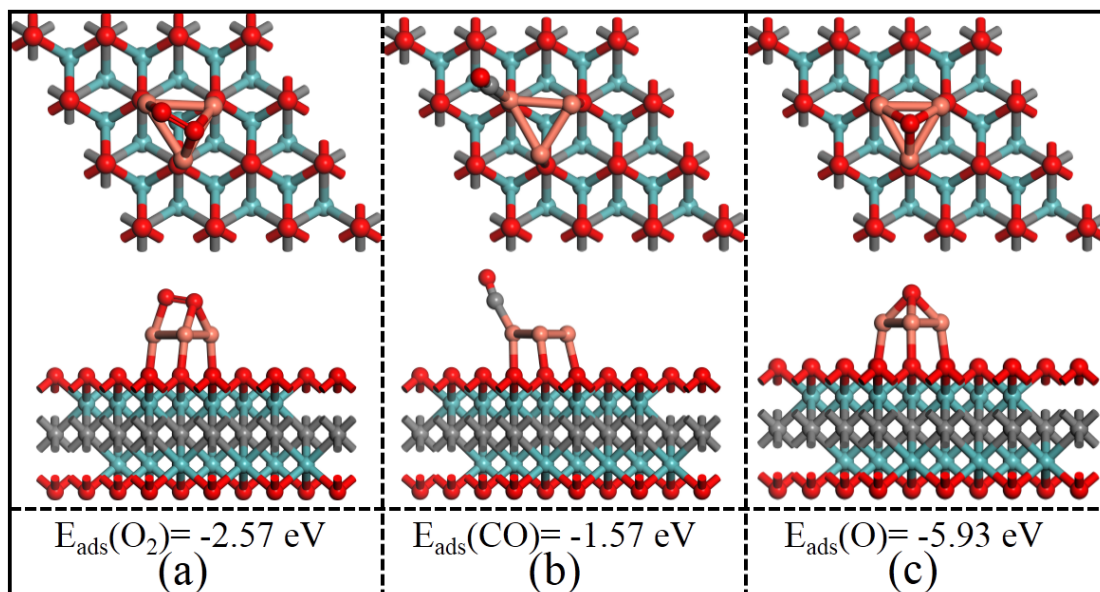


Figure S3. Top and side views of the adsorption configurations and adsorption energies of (a) O_2 , (b) CO , and (c) O on $\text{Cu}_3/\text{p-Mo}_2\text{CO}_2$.

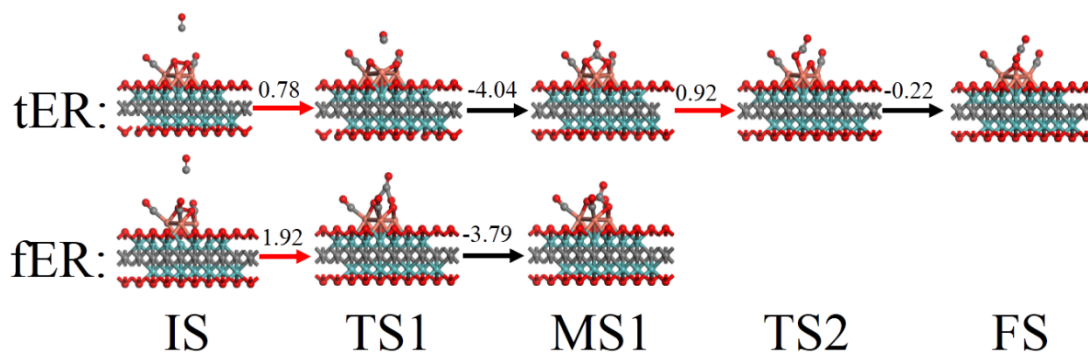


Figure S4. Reaction pathways (side views) of CO oxidation on $\text{Cu}_3/\text{d-Mo}_2\text{CO}_2$ via the tER (t: termolecular, three CO molecules), and fER (f: tetramolecular, four CO molecules) involved in the O_2 -parallel configuration. IS, TS1, MS1, TS2 and FS denote the initial state, first transition state, first intermediate state, second transition state and final state, respectively. The numbers above the red and black arrows represent the activation barriers and reaction energies, respectively. The energy values are shown in unit of eV.

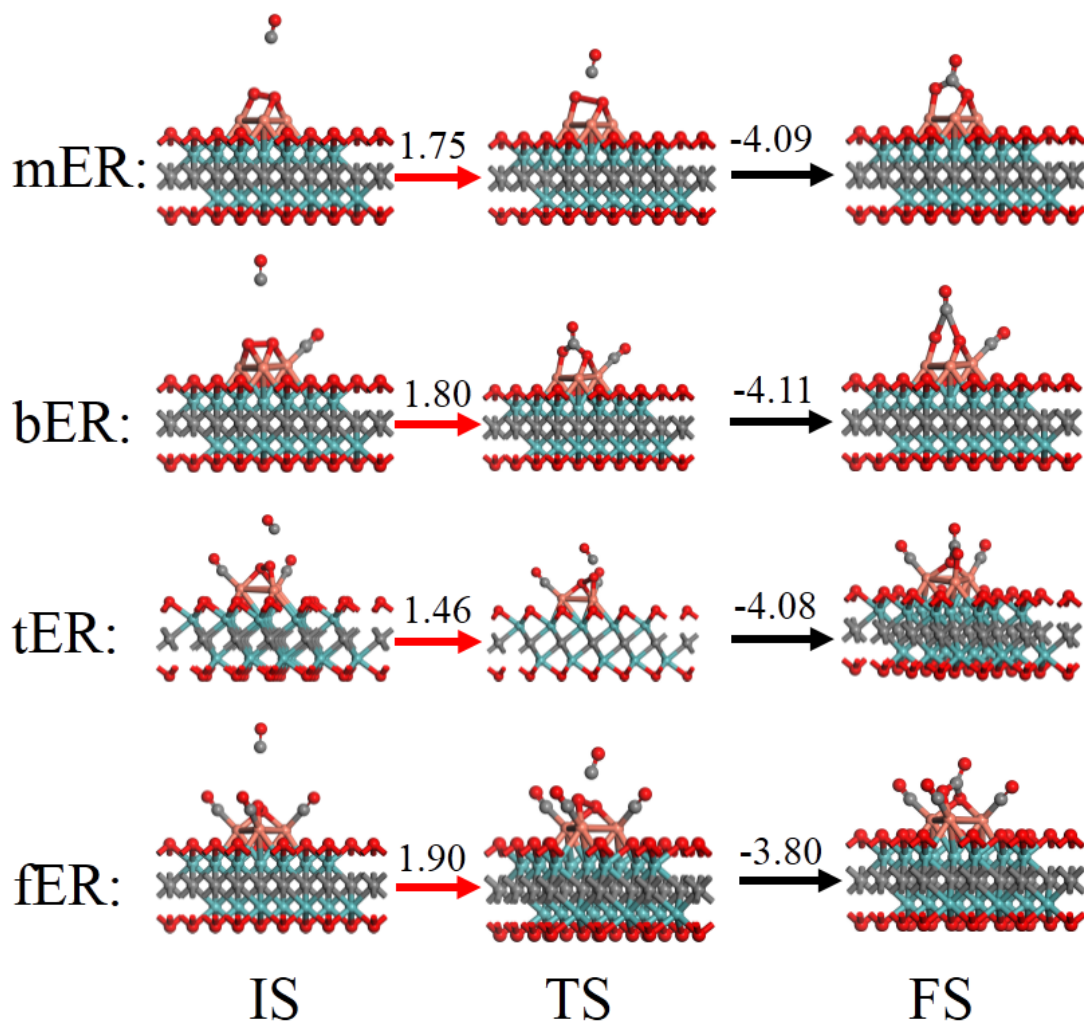


Figure S5. Reaction pathways (side views) of CO oxidation on $\text{Cu}_3/\text{d-Mo}_2\text{CO}_2$ via the mER (m: monomolecular, single CO molecule), bER (b: bimolecular, two CO molecules), tER (t: termolecular, three CO molecules), and fER (f: tetramolecular, four CO molecules) involved in the O_2 -diagonal configuration. IS, TS1, MS1, TS2 and FS denote the initial state, first transition state, first intermediate state, second transition state and final state, respectively. The numbers above the red and black arrows represent the activation barrier and reaction energies, respectively. The energy values are shown in unit of eV.

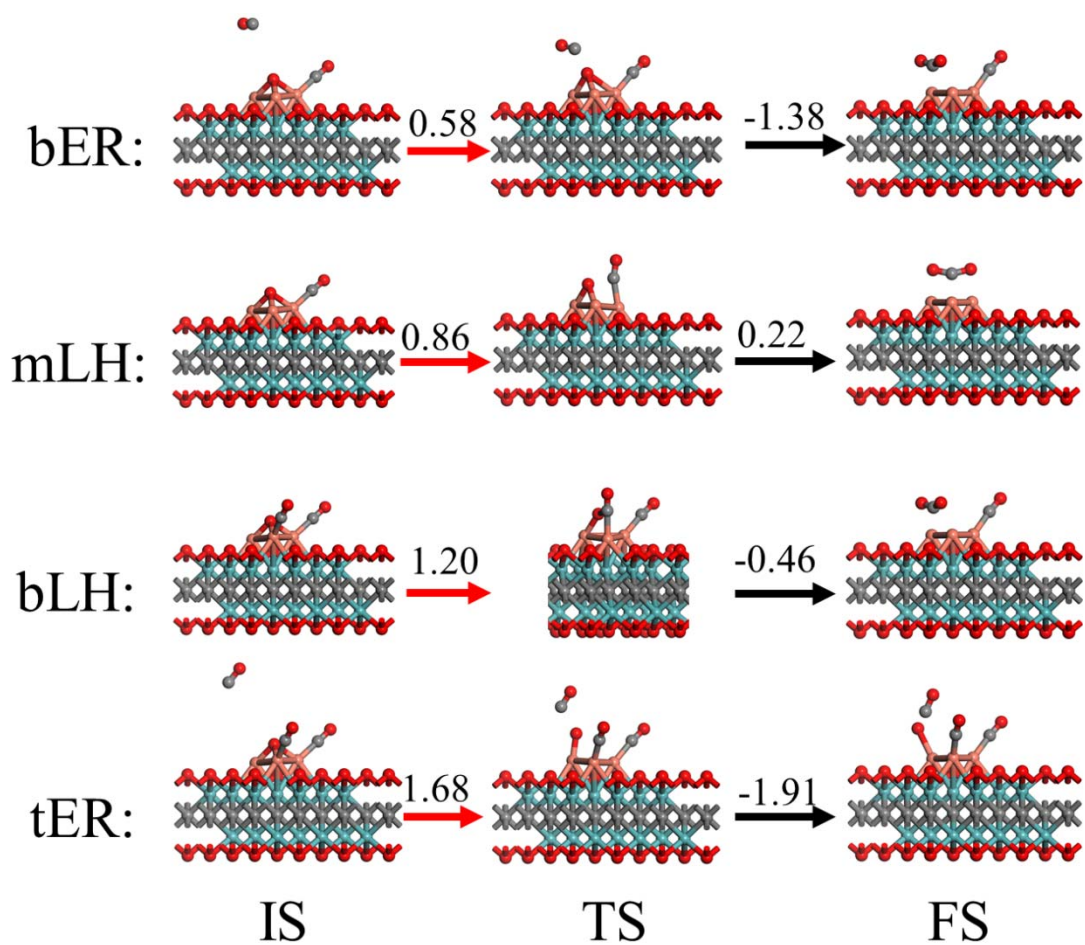


Figure S6. Reaction pathways (side views) of CO oxidation on $\text{Cu}_3/\text{d-Mo}_2\text{CO}_2$ via the bER (b: bimolecular, two CO molecules), mLH (m: monomolecular, single CO molecule), bLH (b: bimolecular, two CO molecules), and tER (t: termolecular, three CO molecules) involved in the O_2 -diagonal configuration. IS, TS1, MS1, TS2, and FS denote the initial state, first transition state, first intermediate state, second transition state and final state, respectively. The numbers above the red and black arrows represent the activation barriers and reaction energies, respectively. The energy values are shown in unit of eV.

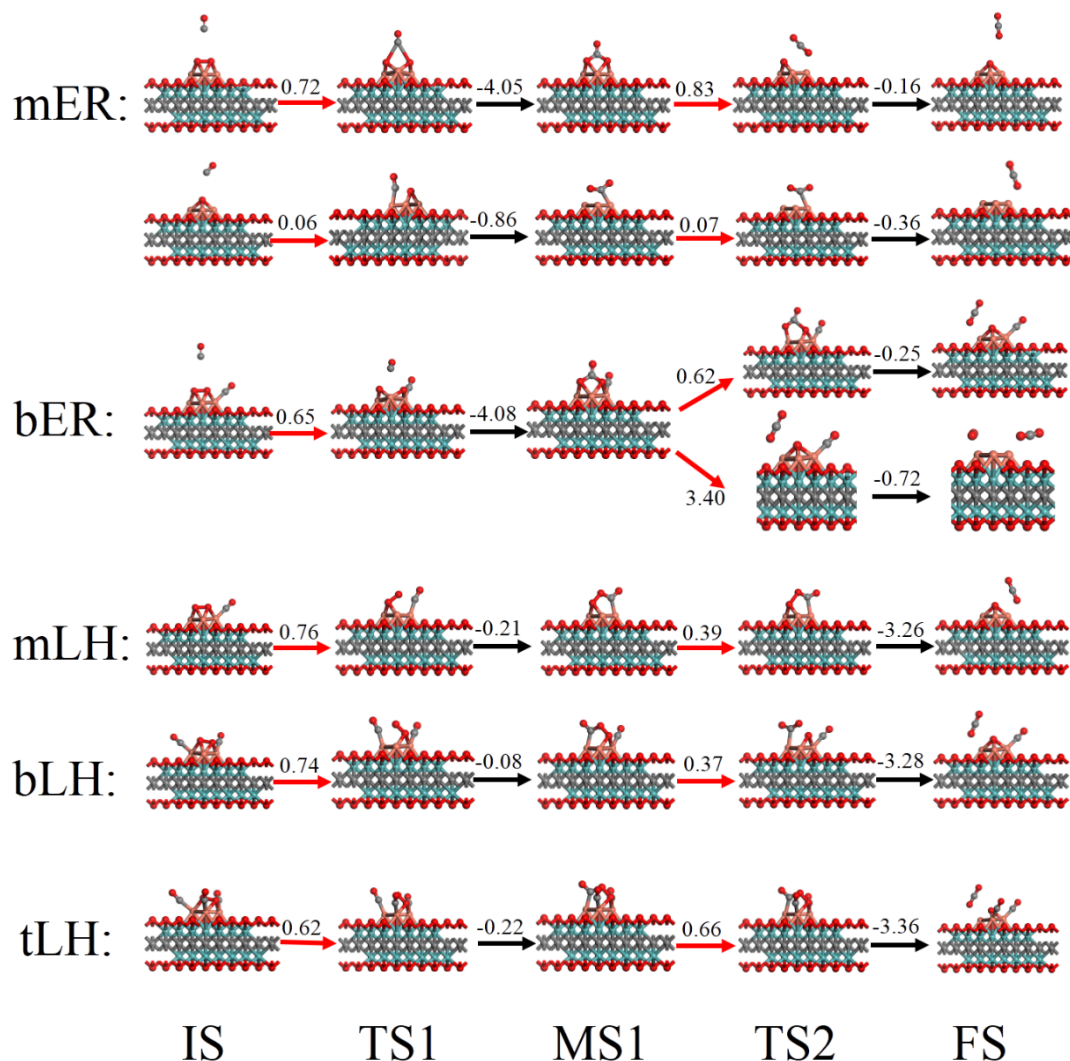


Figure S7. Reaction pathways (side views) of CO oxidation on $\text{Cu}_3/\text{d-Mo}_2\text{CO}_2$ via the mER, bER, mLH, bLH and tLH mechanism involved in the O_2 -parallel configuration, where m, b and t represent monomolecular (only one CO molecule), bimolecular (two CO molecules), and termolecular (three CO molecules), respectively. IS, TS1, MS1, TS2 and FS denote the initial state, first transition state, first intermediate state, second transition state, and final state, respectively. The numbers above to the red and black arrows represent activation barriers and the reaction energies, respectively. The energy values are shown in unit of eV.

Part I. Details of analysis for why we choose Cu₃ cluster on the defective Mo₂CO₂ monolayer.

The three-atom transition metal clusters have been proved with high activity towards many chemical processes based on the first principles calculations, including CO oxidation. For instance, Zeng's group¹ found that the unique triangular Au₃ active site played a vital role in promoting the CO oxidation. Jiang's group² found that Cu₃ active site anchored on MoS₂ played an important role in catalyzing CO oxidation. Li's group³ reported that Fe₃ anchored on Al₂O₃ as a single cluster catalyst exhibited unusual activity for ammonia synthesis. Especially, many excellent works from Sunney Chan's laboratory⁴⁻⁵ demonstrated that Cu₃ active site of tricopper cluster complex within enzyme systems exhibited novel oxygen reduction reaction activity and methanol synthesized activity. Their studies also provided the synthesis methods on enzyme systems. It might be anticipated that these methods would be applicable to prepare Cu₃ on other substrates like Mo₂CO₂, which has many outstanding properties. We also expect that the outstanding properties of Cu₃ active site would be displayed on Mo₂CO₂. Therefore, we chose Cu₃ cluster on Mo₂CO₂ as a single-cluster catalyst to investigate the CO oxidation activity.

The characteristics of the defects at the surface will influence the formation of Cu clusters and their stability shown in Figure S8 and S9. Therefore, we calculated oxygen vacancy formation energies, and found that cluster with three vacancies is likely to form. Only neutral oxygen vacancies were considered with the formation energy defined as:

$$E_{\text{form}} = E_{nV} + nE_{1/2O_2} - E_P \quad (1)$$

where E_{nV} , $E_{1/2O_2}$, E_P , n are the total energies of the monolayer Mo₂CO₂ with oxygen vacancies, half of the O₂ molecule, primitive 2D Mo₂CO₂ and the number of oxygen vacancies, respectively. The formation energy of single oxygen vacancy of Mo₂CO₂ is 3.64 eV as given in our recent work⁶. Various oxygen vacancy configurations ($n = 2, 3$ and 4) are considered in the Figure S8, and the corresponding formation energies for the different configurations are shown in Table S1. Note that, the formation energies are similar when the number of vacancies are the same. However, when the number of oxygen vacancy is up to four, the quite large formation energies may inhibit its formation.

The Cu atoms anchored on the vacancies of the above-mentioned configurations are also shown in the Figure S9. The corresponding average binding energy, adhesion energy and cohesive energy

are calculated according to the equations in the “computational details”, and the calculated results are summarized in the Table S2. According to the previous studies⁷⁻⁸, metal atoms are inclined to aggregate into big clusters if the binding energy are weaker than the bulk cohesive energy. The binding energy of a single Cu atom on the surface with a single vacancy is about 0.16 eV lower than the Cu bulk cohesive energy. That’s to say, Cu atoms have a tendency to aggregate into big cluster instead of keeping isolation. This fact agrees well with the calculated binding energies shown in Table S2 that the energetically favorable configurations are the closed forms (triangular configuration of Figure S9e, quadrangular configuration of Figure S9f and trapezoidal configuration of Figure S9i) with the biggest binding energies. Although the average binding energy per Cu in Figure S9e configuration is the same with the other two configurations displayed as Figure S9f and S9i, the adhesion energy ($E_{\text{Cu-substrate}}$), which represents as a measure of binding strength between the supported atoms and substrate, of Cu₃ shown in Figure S9e is larger than the other two, which guarantees Cu₃ shown in Figure S9e the most stable structure among all the structures ($n \leq 5$). Therefore, Cu₃ cluster in a triangular configuration deposited on defective Mo₂CO₂ substrate would be the most energetically favorable configuration. Moreover, the oxygen vacancy formation energies of $n = 4, 5$ are larger than $n = 3$, we therefore choose triangular oxygen vacancies as the model, which is just compatible to the lowest energy Cu₃ cluster. Moreover, the existence of superficial vacancies of MXene has been confirmed by electron energy loss spectroscopy and atomic-resolution scanning transmission electron microscopy experiments⁹⁻¹⁰. In addition, the lowest energy structures of free Cu_n ($n \leq 5$) clusters are 2D, and the triangular Cu₃ cluster may be prepared by soft-landing cluster method or thermal treatment analogous to the report of Li et al.³.

After considering the formation energy and geometric stability of the supported Cu₃ cluster, we also consider its CO oxidation reactivity. For single Cu atom adsorbed on the defective substrate, the adsorption energies of CO, O₂ and CO₂ are -1.35, -0.53 and -0.59 eV, respectively. The weaker adsorption of O₂ than CO would give rise to the CO-poisoning problem. Meanwhile, the similar adsorption strength of O₂ and CO₂ will make them competitively dominating the active site. Therefore, we speculate the weak activity for CO oxidation on single Cu anchored Mo₂CO₂. When two Cu atoms are anchored on the defective Mo₂CO₂ with the configuration shown in Figure S9a, the long distance between the two Cu atoms make this system possessing the characteristics as the

single Cu anchored system that we do not consider this condition. We therefore consider the other configurations as shown in the Figure S9b. However, the desorption of CO₂ is difficult with reaction barriers of 0.83 eV (Figure S10), which is much bigger than that on Cu₃/d-Mo₂CO₂ (0.07 eV). Therefore, the one or two Cu atoms embedded systems possess poor activity and we do not consider them. Even though the sizes of the oxygen vacancies on Mo₂CO₂ surface are very large ($n \geq 4$), after the deposition of three Cu atoms, the O₂ molecule can automatically dissociate with the dissociative oxygen atoms filling the vacancies, resulting in the sCu₃/d-Mo₂CO₂ configuration. Therefore, we focus on considering Cu₃/d-Mo₂CO₂ configuration.

To sum up, some three-atom transition metal clusters have been proved with high activity towards many chemical processes based on the first principles calculations, including CO oxidation¹⁻³. Especially, many excellent works from Sunney Chan's laboratory⁴⁻⁵ demonstrated that Cu₃ active site of tricopper cluster complex within enzyme systems exhibited novel oxygen reduction reaction activity and methanol synthesized activity. Their studies also provided the synthesis methods on enzyme systems. It might be anticipated that these methods would be applicable to prepare Cu₃ on other substrates like Mo₂CO₂, which has many outstanding properties. We expect that the outstanding properties of Cu₃ active site would be displayed on Mo₂CO₂. Therefore, we chose Cu₃ cluster on Mo₂CO₂ as a single-cluster catalyst to investigate the CO oxidation activity. Moreover, the existence of superficial vacancies of MXene has been confirmed by electron energy loss spectroscopy and atomic-resolution scanning transmission electron microscopy experiments⁹⁻¹⁰. The lowest energy structures of free Cu₃ cluster are 2D, and the triangular Cu₃ cluster may be prepared by soft-landing cluster method or thermal treatment analogous to the report of Li et al.³ Even though the sizes of the oxygen vacancies on Mo₂CO₂ surface are very large ($n \geq 4$), after the deposition of three Cu atoms, the O₂ molecule can automatically dissociate with the dissociative at the vacancies left with the dissociative oxygen atoms filling the vacancies, resulting in the Cu₃/d-Mo₂CO₂ configuration. Besides, the oxygen vacancy formation energies of $n = 4, 5$ are larger than that of $n = 3$, we therefore choose triangular oxygen vacancies as the model, which is just compatible to the Cu₃ cluster. Therefore, we focus on considering the Cu₃/d-Mo₂CO₂ configuration.

Here, we expect triangular Cu₃ cluster on the defective Mo₂CO₂ substrate namely Cu₃/d-Mo₂CO₂ as shown in Figure 1b or S9e is the best catalyst according to the formation energy,

geometric stability and reaction activity. We therefore only consider the Cu_3 instead of Cu_2 or Cu_4 or others. Additionally, the comparison with reference 33 is considered for the point that although there is no precise report about Cu cluster on Mo_2CO_2 so far, many metal nanoparticles (such as Pt, Au, Ag and so on) have been successfully synthesized on the MXene according to the hydrothermal synthesis, sputtering, atomic layer deposition (ALD) methods and one-step soft solution processing¹¹⁻¹⁴. We hope the synthesis method in reference 33 is also applicable for the synthesis of Cu_3 cluster on Mo_2CO_2 since the flexibility and multiformity of synthesized composites on MXenes. The synthetic methods are the main goals here instead of the reaction processes. The chemical processes might be investigated in the next work.

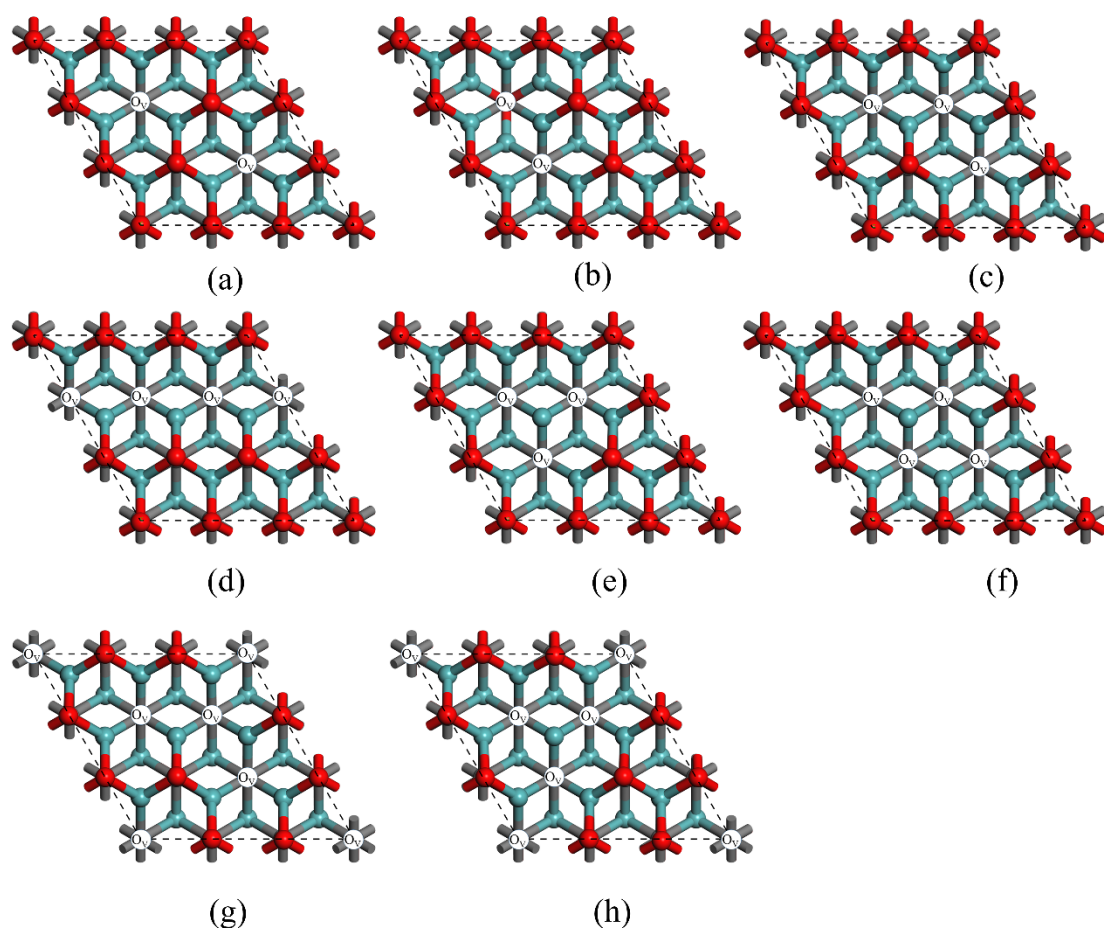


Figure S8. Top views of the different oxygen vacancy configurations ((a-b): $n = 2$; (c-e): $n=3$ and (f-h): $n=4$). The white areas represent oxygen vacancies.

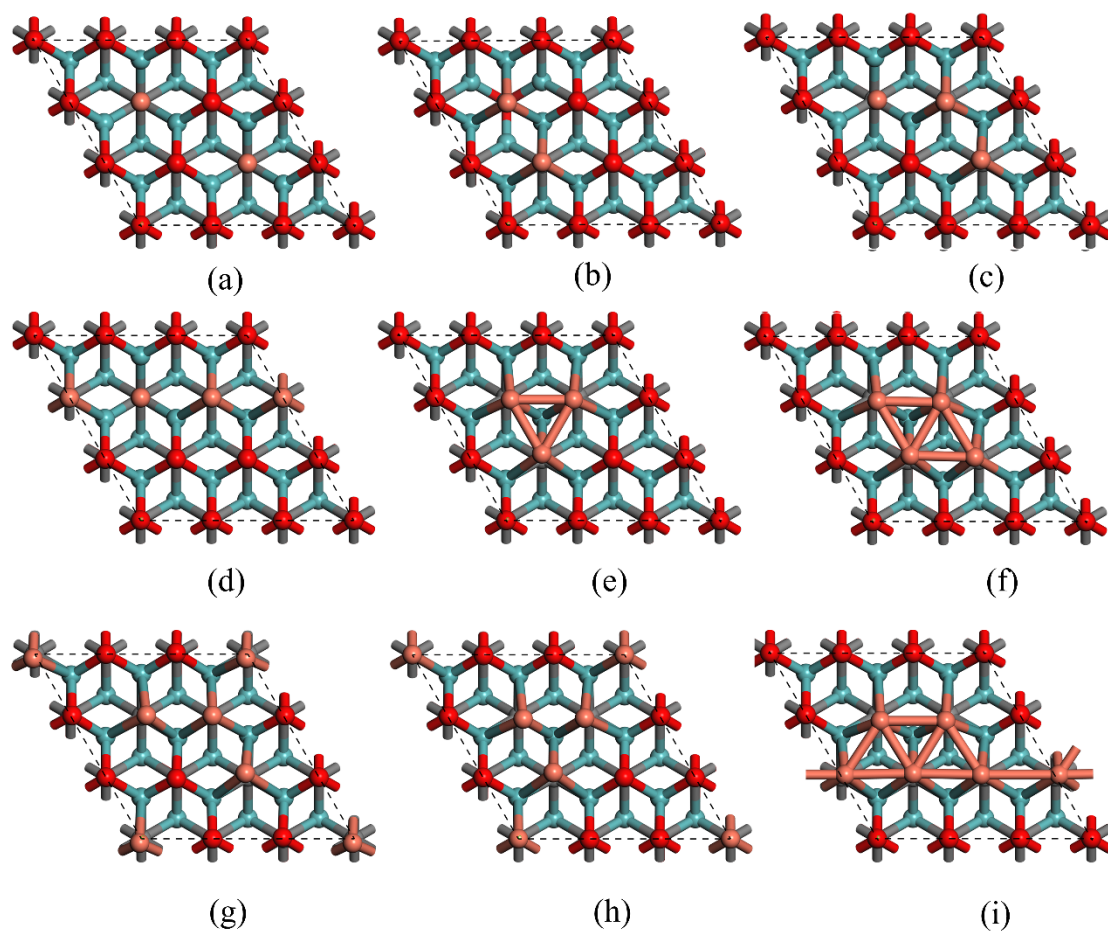


Figure S9. (a~h) Top views of the different adsorption configurations of Cu atoms anchor on various vacancies. (i) The lowest adsorption configuration for Cu_5 on the substrate.

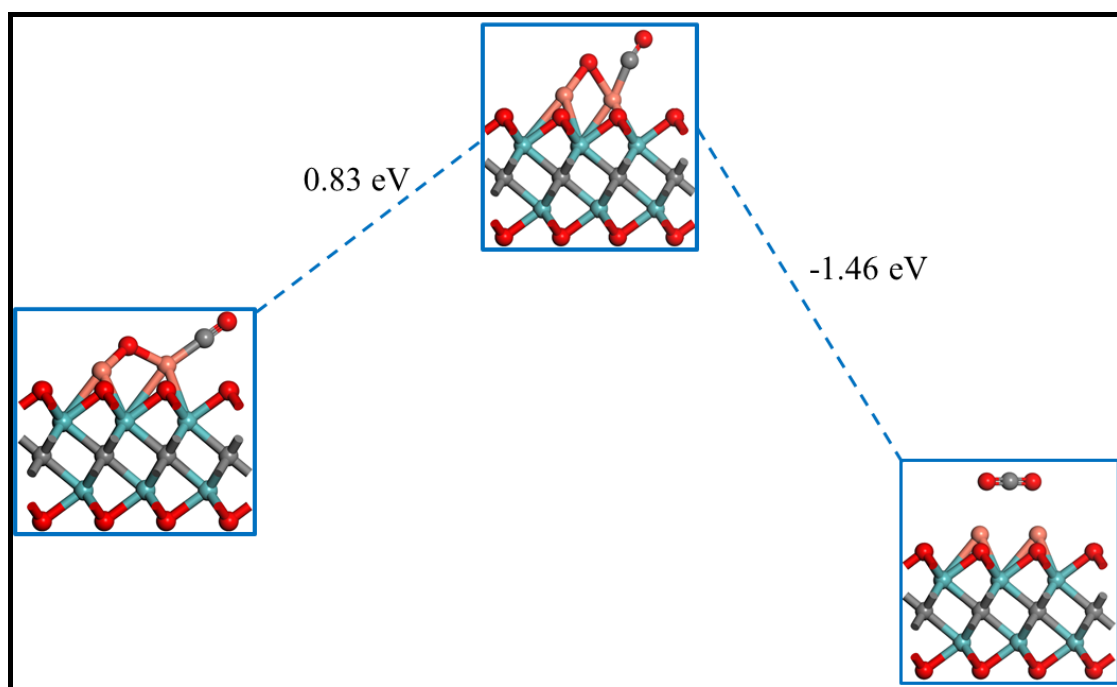


Figure S10. The reaction processes of the formation of CO₂ on two near Cu atoms embedded Mo₂CO₂ system (Figure S9b).

Table S1. The formation energies $E_{\text{form}}(\text{nO}_v)$ for various oxygen vacancy configurations (n = 2, 3 and 4) shown in Figure S8.

Configurations	$E_{\text{form}}(\text{nO}_v)$ (eV)
Figure a	7.44
Figure b	7.39
Figure c	11.31
Figure d	11.36
Figure e	11.40
Figure f	15.40
Figure g	15.32
Figure h	15.45

Table S2. The calculated average binding energy (E_b), adhesion energy ($E_{\text{Cu-substrate}}$), and cohesive energy ($E_{\text{Cu-Cu}}$) for the supported Cu atoms on vacancies configurations shown in Figure S9. The energies are shown in the unit of eV.

Configurations	E_b (eV)	$E_{\text{Cu-substrate}}$	$E_{\text{Cu-Cu}}$
Figure a	-3.66	-3.61	-0.05
Figure b	-3.63	-2.83	-0.80
Figure c	-3.56	-2.56	-1.00
Figure d	-3.50	-2.34	-1.16
Figure e	-3.75	-2.56	-1.19
Figure f	-3.75	-2.26	-1.49
Figure g	-3.48	-2.44	-1.04
Figure h	-3.66	-2.22	-1.44
Figure i	-3.76	-2.06	-1.70

Part II. More detailed derivations about the reliable activation barrier to depict the activity.

Generally, the computed reaction barriers (ΔE s) was used to compute the forward and backward reaction rates. For surface reactions, the reaction rates (k) for elementary reaction steps were determined by the Eyring equation¹⁵:

$$k = Ae^{\frac{-\Delta E}{K_b T}} \quad (2)$$

where ΔE , K_b , T and A are the reaction barrier, Boltzmann constant, temperature and prefactor, respectively. For convenience, the pre-factor A is always set to a constant for all the elementary surface reactions¹⁶⁻¹⁷. Obviously, the reaction rate k is exponentially related to reaction barrier. The critical reaction barrier for CO oxidation reaction is about 1.0 eV at room temperature according to previous reports¹⁷⁻¹⁸. In fact, for convenience, researches are always choosing reaction barrier (ΔE) as the effective judgment for results¹⁹⁻²¹.

Part III. Detailed calculated methods for non-neutral defects on Mo₂CO₂ monolayer.

It is relatively complicated to obtain the formation energies of non-neutral defects. The calculated methods are listed below as that given by Zhang and Northrup²². The formation energy ($\Delta H_{\text{form}}(\text{O}^Q)$) of a defect O in the charge state Q is defined as

$$\Delta H_{\text{form}}(\text{O}^Q) = E_{\text{tot}}(\text{O}^Q) - \sum_X n_X \mu_X + Q(\mu_e + E_v) + M(Q) \quad (3)$$

where μ_e is the electron chemical potential (equaling the Fermi level E_f in the T = 0 K calculations), $E_{\text{tot}}(\text{O}^Q)$ is the total energy of the defective supercell in the charge state Q, E_v is the top valence band energy, $M(Q)$ is the defect-dependent multipole corrective term of reference²³ [Phys. Rev. B 1995, 51 (7), 4014-4022], n_X and μ_X are the number of involved atoms ($X = \text{Mo}, \text{C}, \text{O}$) and their chemical potentials, respectively. The chemical potential of involved atoms are not independent variables, since their species are in equilibrium with the Mo₂CO₂ bulk compound. Their chemical potentials must satisfy the following condition:

$$\mu_{\text{Mo}_2\text{CO}_2}^{\text{bulk}} = 2\mu_{\text{Mo}} + \mu_{\text{C}} + 2\mu_{\text{O}} \quad (4)$$

Part IV. The influence of the adsorbed reactants on the support at the vicinity of the Cu₃ cluster.

As shown in Figure 4, O₂ has a stronger binding strength than CO and therefore will first dominates the active site when they are occurring simultaneously. However, the second O₂ has a weak adsorption at the active site and CO will overwhelm the second O₂ and dominates the active site as displayed in Table 2. The weak adsorption of the second O₂ is found from the fact that when we put an O₂ slightly away from the active site, it will be physically adsorbed on the surface as displayed in Figure S11. The Cu₃ cluster keeps neutral when the first O₂ dominates the active site and the second O₂ appears in the vicinity of the active site simultaneously. The second O₂ has a weak adsorption at the active site and CO molecules will overwhelmingly dominate the active site as displayed in Table 2.

However, no matter where the CO molecules initially are, they intend to diffuse to the Cu₃ active site as shown in Figure S12 of the different adsorption sites. In other word, CO would not be adsorbed at the vicinity of the Cu₃ cluster and will rapidly take part in the reaction. So, the adsorption of the reactants on the support would not influence the charge transfer between the support and the cluster, and not influence the reaction path and the oxidation ability of the cluster.

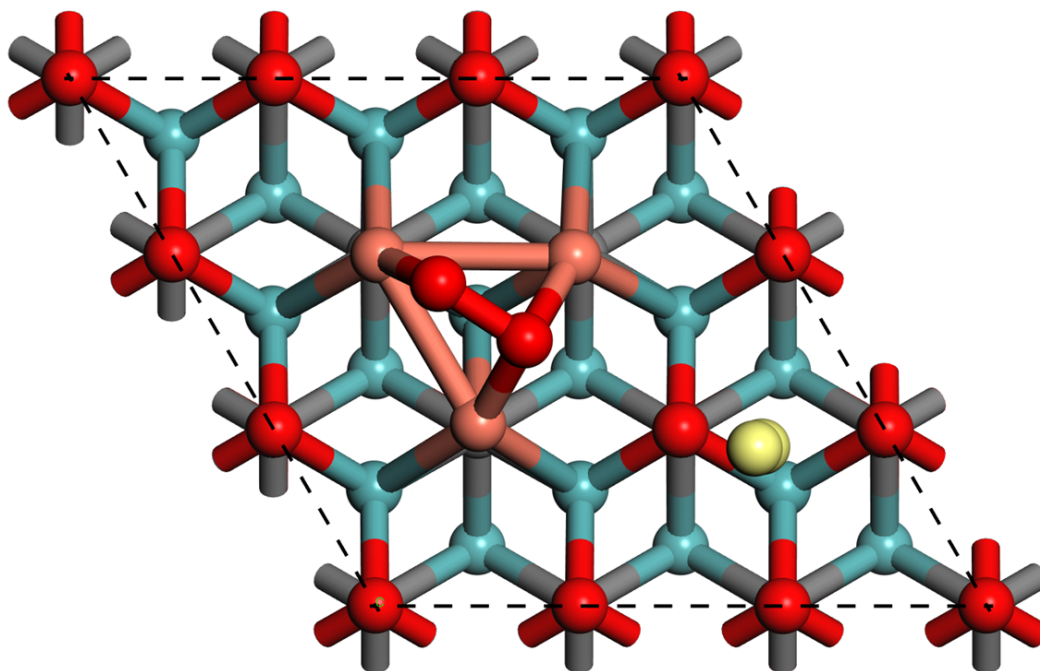


Figure S11. The geometric structure of the first O₂ dominates the active site and the second O₂ physically adsorbs in the vicinity of the surface. The red, blue, grey, and orange balls represent

the O, Mo, C, and Cu atoms, respectively. The yellow balls represent the second adsorbed O₂.

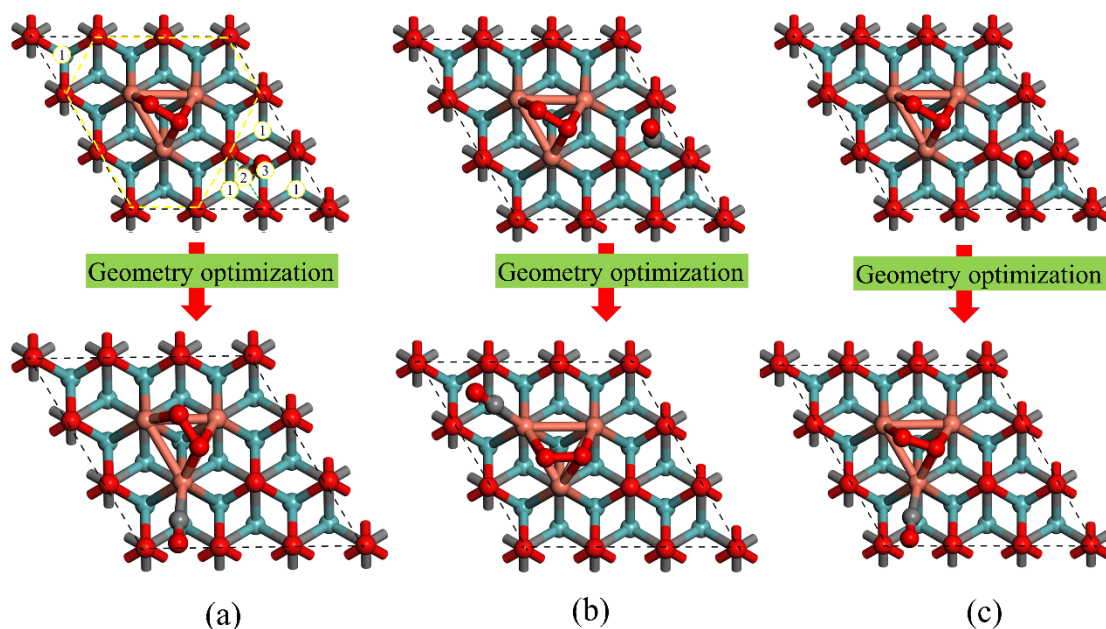


Figure S12. The structures of the coadsorbed structures of (CO + O₂) before and after optimizing geometric structures. One O₂ is first diagonally adsorbed on the Cu₃ active site, and one CO molecule is physically adsorbed at the vicinity of the different active sites, which are labeled as 1, 2 and 3. (a-c) Structures shown in the upper panels with CO molecule adsorbs at sites 3, 1, and 2 before geometry optimization, and the corresponding structures after geometry optimization shown in the bottom panels.

Part V. The reaction mechanisms involved in the O₂-parallel configuration.

ER Mechanism. Because the adsorption energies of O₂ is lower than CO, we guess that O₂ can dominantly take up the active sites when mixed gases of CO and O₂ are injected into the catalyst. Therefore, the CO oxidation reaction would follow the ER mechanism (Figure S7, mER), where the first physically adsorbed CO gradually approaches the pre-adsorbed O₂ and then forms the CO₃ intermediate with a barrier of 0.72 eV. The dissociation of the CO₃ intermediate to release the first CO₂ is slightly harder with the activation barrier of 0.83 eV. To proceed, the remained atomic O can be easily removed by oxidizing with the forthcoming CO and releasing the second CO₂ with the maximum barrier of 0.07 eV as shown in Figure S7. Besides, more than one CO molecules can be adsorbed according to the above calculation. The physically adsorbed CO approaching the substrate with the co-adsorbed oxygen and one CO is assumed as bER mechanism. The detailed reaction pathways can be seen in bER of Figure S7. There appears a CO promotion effect to form CO₃ intermediate with a smaller activation barrier of 0.65 eV, and then desorb first CO₂ molecule with the reaction heat of 4.33 eV releasing in the whole process. In contrast, the formation of two CO₂ at the same time is difficult with a huge barrier of 3.40 eV. Also, when CO molecules at high concentration, the cases that a physically adsorbed CO increasingly closes to the surface with two (tER in Figure S4) or three (fER in Figure S4) CO molecules co-adsorbed with O₂ at parallel configuration on the substrate are considered as shown in Figure S4. The above two cases may be hard to happen as compared with the mER and bER mechanisms shown in Figure S7, because of the high rate-determining energy barriers (0.92 and 1.92 eV) for forming the first CO₂ (MS1 → FS, in Figure S4) and the CO₃ intermediate (IS → MS1, in Figure S4), respectively.

LH Mechanism. The LH mechanisms of one, two, or three CO molecules co-adsorbed with O₂ at parallel configuration on the substrate are shown at Figure S7 as mLH, bLH and tLH, respectively. For the mLH mechanism, one adsorbed CO can react smoothly with the co-adsorbed O₂ to construct the intermediate MS1 (in mLH) and release the first CO₂ (MS1 → FS, in Figure S7) with the barriers of 0.76 and 0.39 eV, respectively. As for the bLH mechanism, it has the similar effect to the mLH mechanism, indicating that the co-adsorption of more than one CO molecules cannot obviously promotes the reaction with the rate-limiting step barriers (0.74 eV) for forming the OOCO*

intermediate state (MS1 in bLH of Figure S7). After releasing a CO₂, atomic O and a co-adsorbed CO are left on the Cu₃ active site. But the release of the second CO₂ is easier via bER than mLH mechanism through comparing the energy barriers (0.58 vs 0.86 eV) as shown in Figure S6. In addition, since the same structure for MS1 in bLH in Figure S7 and Figure 5, the release of two CO₂ is considered shown in Figure 5 (MS1 → FS) with the barrier of 0.38 eV. In other word, in the bLH mechanism, the release of two CO₂ at the same time is preferred while the rate-limiting step is still the formation of OOCO* intermediate (MS1 in bLH of Figure S7). For the case of three CO co-adsorbed with the O₂ at parallel configuration on the substrate, the reaction called tLH mechanism in Figure S7 is smoother with a smaller barrier (0.62 eV). But the release of the first CO₂ has a slightly higher barrier than those of the mLH and bLH mechanisms (0.66 eV vs 0.39 and 0.37 eV). Once the first CO₂ is released, there leave an atomic O and two CO co-adsorbed on the substrate. However, the release of the second CO₂ is greatly harder with the barriers of 1.20 and 1.68 eV in the bLH and tER mechanisms shown in Figure S6. We also take into account the release of two CO₂ at the same time. Due to the same configuration of MS1 in the tLH mechanism (Figure S7 and 5), the whole process is shown in the tLH (MS1 → FS) in Figure S7 with the barrier of 0.57 eV.

In conclusion, more CO molecules co-adsorbed with the O₂ at parallel configuration could not always accelerate the reaction. The bER mechanism is more favorable than the other ER mechanisms according to the energy barriers, because it may proceed a big cycle to release CO₂ (bER (Figure S7) → bER (Figure S6) → bLH (Figure S7, release two CO₂ at the same time) or tLH (Figure S7, release two CO₂ at the same time) → bLH (Figure S7, release two CO₂ at the same time)). When the O₂ pre-adsorbs at parallel configuration, no matter how the reaction proceeds, the rate-limiting step of the whole reaction process is still the formation of OCOO* intermediate (MS1 in bLH of Figure S7). It may proceed with bLH mechanism directly, or carry out the tLH mechanism first to form two CO₂ simultaneously and then continually proceed with bLH mechanism with the same rate-limiting energy barrier of 0.74 eV.

Table S3. Rate constant k (s^{-1}) for the elementary reactions on $\text{Cu}_3/\text{d-Mo}_2\text{CO}_2$ via the bLH mechanism involved in the O_2 -diagonal configuration for the formation of two CO_2 (FS) simultaneously.

T (K)	IS-MS1	MS1-FS
	($2\text{CO} + \text{O}_2 \rightarrow \text{OCOO} + \text{CO}$)	($\text{OCOO} + \text{CO} \rightarrow 2\text{CO}_2$)
200	7.6114×10^{-6}	2.7380×10^3
298.15	7.0150×10^0	3.8497×10^6
400	8.7244×10^3	1.6547×10^8
500	5.6570×10^5	1.4962×10^9

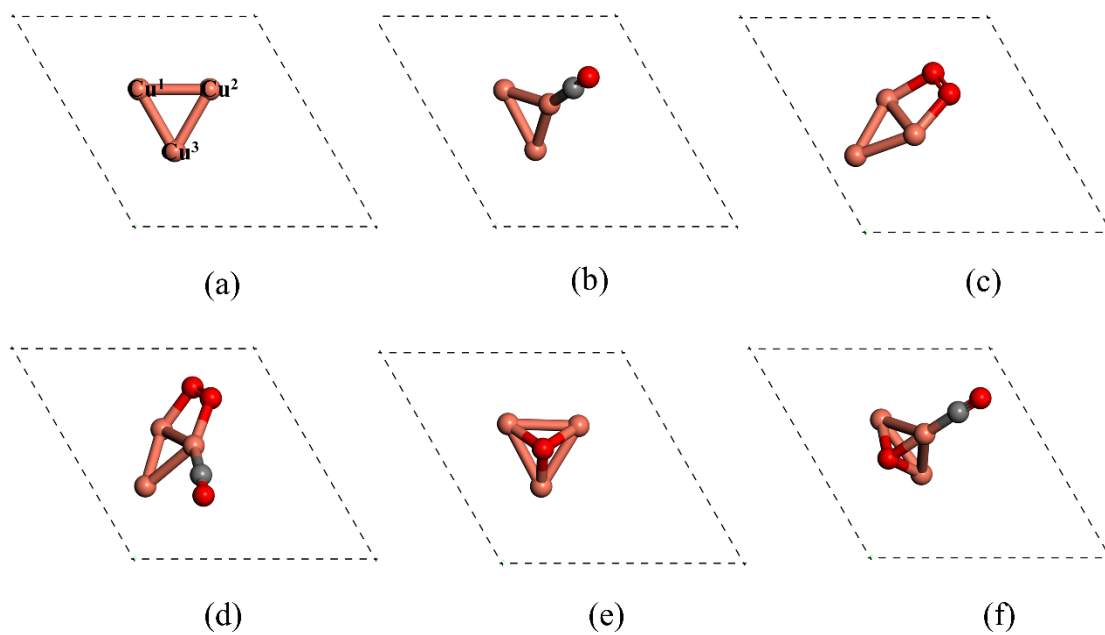


Figure S13 (a) Optimized triangular isolated Cu₃ cluster. (b-f) The geometric structures of CO oxidation intermediates adsorbed on Cu₃ cluster.

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